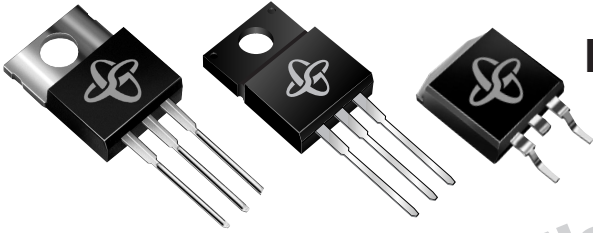
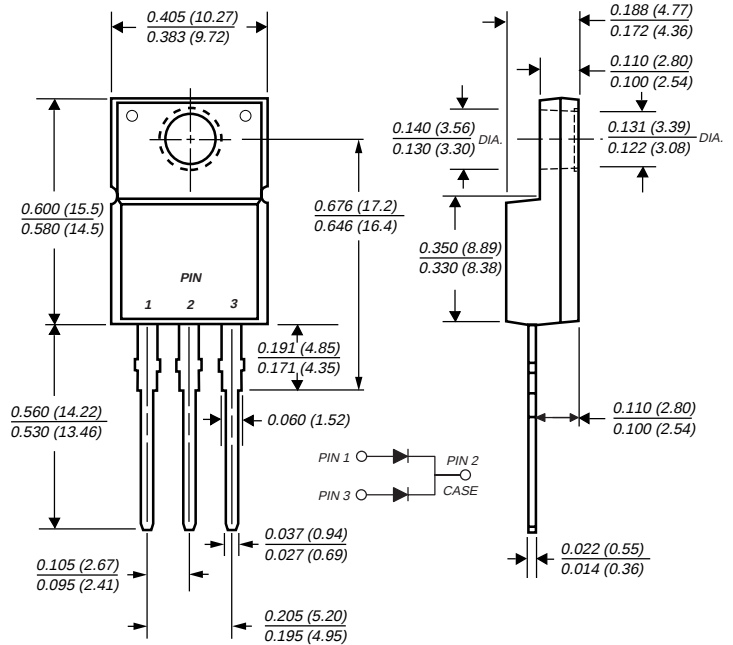


MBR10H100CT, MBRF10H100CT & MBRB10H100CT Series Dual High-Voltage Schottky Rectifiers

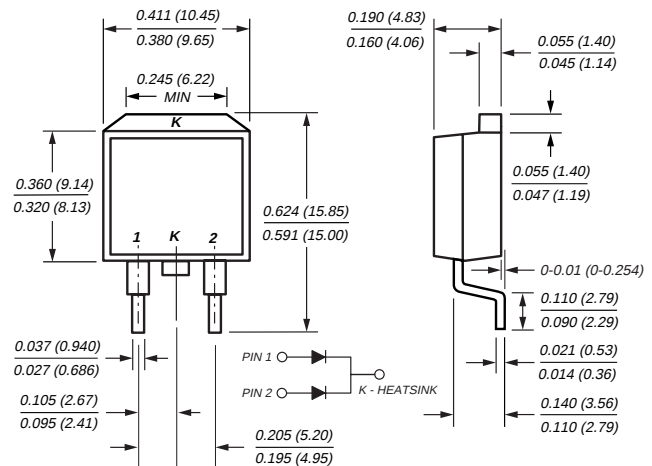


Reverse Voltage 90 to 100V
Forward Current 10A

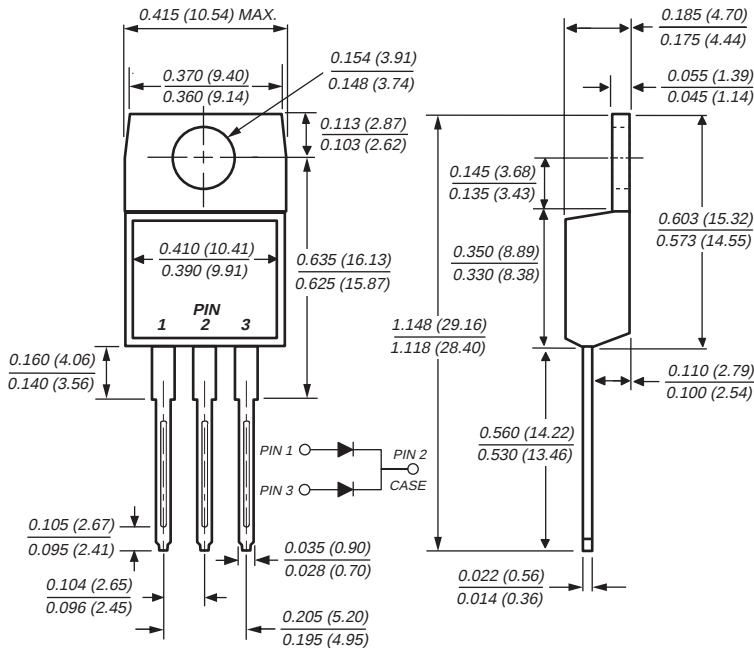
ITO-220AB (MBRF10H90CT, MBRF10H100CT)



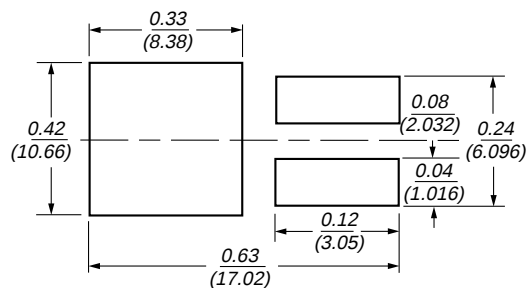
TO-263AB (MBRB10H90CT, MBRB10H100CT)



TO-220AB (MBR10H90CT, MBR10H100CT)



Mounting Pad Layout TO-263AB



Dimensions in inches and (millimeters)

Mechanical Data

Case: JEDEC TO-220AB, ITO-220AB & TO-263AB
molded plastic body

Terminals: Plated leads, solderable per MIL-STD-750, Method 2026

High temperature soldering guaranteed:
250°C/10 seconds, 0.25" (6.35mm) from case

Polarity: As marked

Mounting Position: Any

Mounting Torque: 10 in-lbs maximum

Weight: 0.08oz., 2.24g

Features

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Dual rectifier construction, positive center tap
- Metal silicon junction, majority carrier conduction
- Low power loss, high efficiency
- Guardring for overvoltage protection
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

MBR10H100CT, MBRF10H100CT & MBRB10H100CT Series

Dual High-Voltage Schottky Rectifiers

Maximum Ratings (T_C = 25°C unless otherwise noted)

Parameter	Symbol	MBR10H90CT	MBR10H100CT	Unit
Maximum repetitive peak reverse voltage	V _{RRM}	90	100	V
Working peak reverse voltage	V _{RWM}	90	100	V
Maximum DC blocking voltage	V _{DC}	90	100	V
Maximum average forward rectified current <i>Total device at T_C = 105°C Per leg</i>	I _{F(AV)}	10 5		A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method) per leg	I _{FSM}	150		A
Peak repetitive reverse current per leg at t _p = 2μs, 1KHz	I _{RRM}	0.5		A
Voltage rate of change (rated V _R)	dv/dt	10,000		V/μs
Operating junction and storage temperature range	T _J , T _{STG}	-65 to +150		°C
RMS Isolation voltage (MBRF type only) from terminals to heatsink with t = 1 second, RH ≤ 30%	V _{ISOL}	4500 ⁽¹⁾ 3500 ⁽²⁾ 1500 ⁽³⁾		V

Electrical Characteristics (T_C = 25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Maximum instantaneous forward voltage per leg ⁽⁴⁾ at I _F = 5.0A, T _J = 25°C at I _F = 5.0A, T _J = 125°C at I _F = 10A, T _J = 25°C at I _F = 10A, T _J = 125°C	V _F	0.76 0.61 0.85 0.71	V
Maximum reverse current per leg at working peak reverse voltage (Note 4) T _J = 25°C T _J = 100°C	I _R	3.5 4.5	μA mA

Thermal Characteristics (T_C = 25°C unless otherwise noted)

Parameter	Symbol	MBR	MBRF	MBRB	Unit
Typical thermal resistance per leg	R _{θJC}	2.2	4.2	2.2	°C/W

Notes:

- (1) Clip mounting (on case), where lead does not overlap heatsink with 0.110" offset
- (2) Clip mounting (on case), where leads do overlap heatsink
- (3) Screw mounting with 4-40 screw, where washer diameter is ≤ 4.9 mm (0.19")
- (4) Pulse test: 300μs pulse width, 1% duty cycle



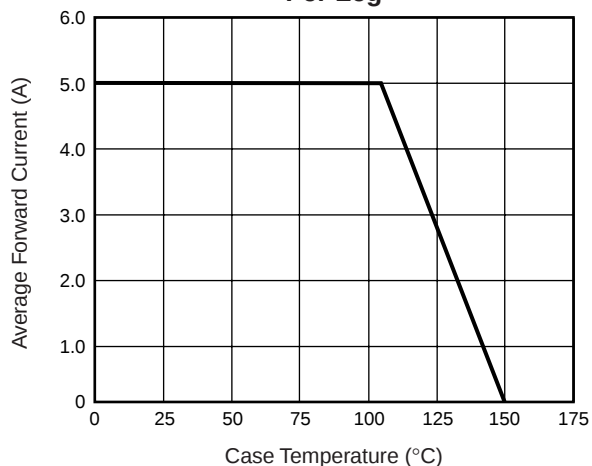
GENERAL
SEMICONDUCTOR®

MBR10H100CT, MBRF10H100CT & MBRB10H100CT Series

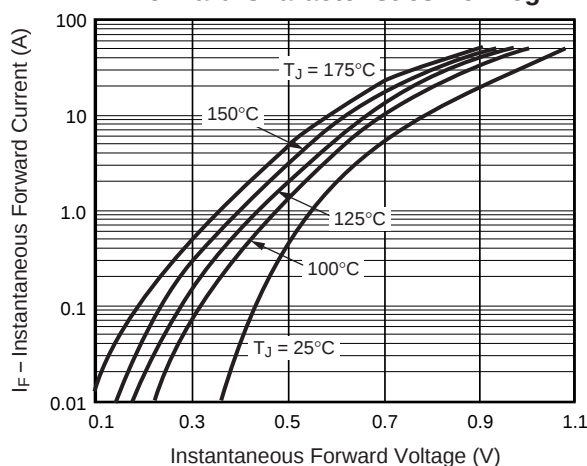
Dual High-Voltage Schottky Rectifiers

Ratings and Characteristic Curves ($T_A = 25^\circ\text{C}$ unless otherwise noted)

**Fig. 1 – Forward Derating Curve
Per Leg**



**Fig. 2 – Typical Instantaneous
Forward Characteristics Per Leg**



**Fig. 3 – Typical Reverse
Characteristics Per Leg**

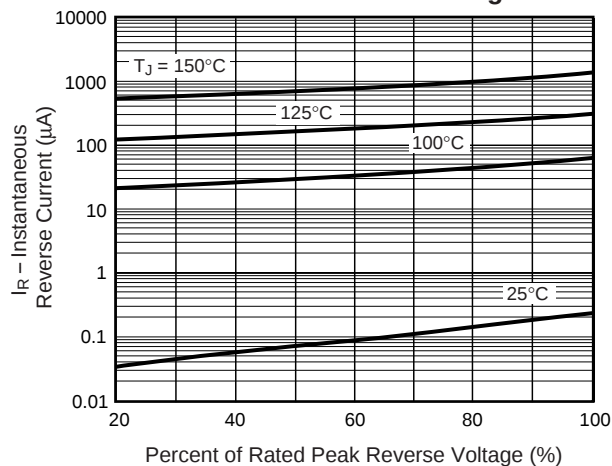
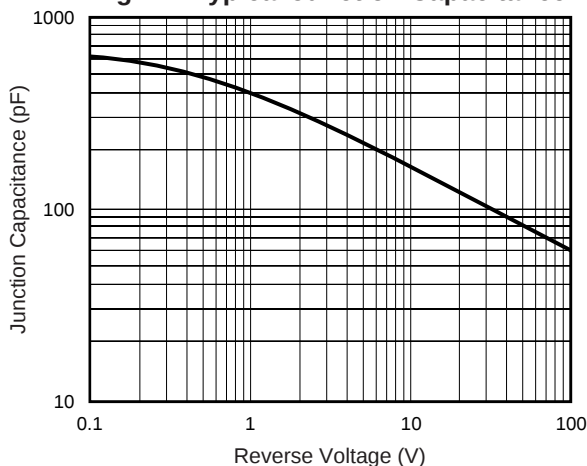


Fig. 4 – Typical Junction Capacitance



**Fig. 5 – Typical Transient
Thermal Impedance Per Leg**

